Philips Components-Signetics

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82LHS191 16K-bit TTL bipolar PROM

DESCRIPTION

The 82LHS191 is field programmable, meaning that custom patterns are immediately available by following the Signetics Generic II fusing procedure. The 82LHS191 is supplied with all outputs at a logical High. Outputs are programmed to a logic Low level at any specified address by fusing the vertical junction matrix.

This device includes on-chip decoding and 3 Chip Enable inputs for ease of memory expansion. It features 3-State outputs for optimization of word expansion in bused organizations.

Ordering information can be found on the following page.

The 82LHS191 devices are also processed to military requirements for operation over the military temperature range. For specifications and ordering information consult the Signetics Military Data Book.

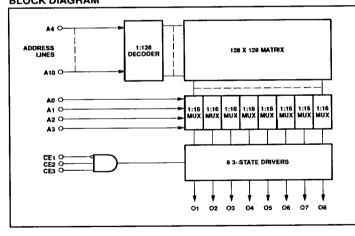
FEATURES

- Address access time: 35ns max
- Power dissipation: 32μW/bit typ
- Input loading: –250µA max
- Three Chip Enable Inputs
- On-chip address decoding
- No separate fusing pins
- Unprogrammed outputs are High level
- Fully TTL compatible
- Outputs: 3-State

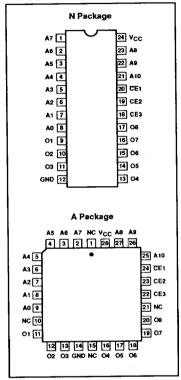
APPLICATIONS

- Prototyping/volume production
- Sequential controllers
- Microprogramming
- Hardwired algorithms
- Control store
- Random logic
- Code conversion

BLOCK DIAGRAM



PIN CONFIGURATIONS



16K-bit TTL bipolar PROM (2048 \times 8)

82LHS191

ORDERING INFORMATION

PACKAGE DESCRIPTION	ORDER CODE		
24-pin Plastic Dual-In-Line 600mil-wide	N82LHS191 N		
24-pin Plastic Dual-In-Line 300mil-wide	N82LHS191 N3		
28-pin Plastic Leaded Chip Carrier 450mil-square	N82LHS191 A		

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT V _{DC}	
V _{CC}	Supply voltage	+7		
V _{IN}	Input voltage	+5.5	V_{DC}	
Vo	Output voltage Off-State	+5.5	V _{DC}	
T _{amb}	Operating temperature range	0 to +75	° C	
T _{stg}	Storage temperature range	-65 to +150	°C	

DC ELECTRICAL CHARACTERISTICS

 $0^{\circ}C \leq T_{amb} \leq +75^{\circ}C, 4.75V \leq V_{CC} \leq 5.25V$

I			LIMITS			
SYMBOL PARAMETER		TEST CONDITIONS ^{1,2}	Min	Typ ⁴	Max	UNIT
Input voltag	je					
V _{IL}	Low ³				0.8	٧
V _{IH}	High ³		2.0			٧
V _{IC}	Clamp	I _{IN} = -18mA		-0.8	-1.2	٧
Output volt	age					
		CE ₁ = Low, CE _{2,3} = High				
VOL	Low	I _{OUT} = 16mA			0.5	ν
V _{OH}	High	I _{OUT} = -2mA	2.4		1	٧
Input curre	nt					
I _{IL}	Low	V _{IN} = 0.45V			-250	μА
l _{iH}	High	$V_{IN} = 5.25V$			40	μΑ
Output curi	rent					
loz	Hi–Z state	CE ₁ = High, CE _{2.3} = Low, V _{OUT} = 0.5V			-40	μА
		$\overline{CE}_1 = \text{High, } CE_{2,3} = \text{Low, } V_{OUT} = 5.25V$		1	40	
los	Short circuit ³	CE ₁ = Low, CE _{2,3} = High, V _{OUT} = 0V -15			-70	mA
Supply curi	rent ⁵					
lcc		V _{CC} = 5.25V		100	110	mA
Capacitano	e					
		CE ₁ = High, CE _{2,3} = Low				
		$V_{CC} = 5.0V$				
CIN	Input	$V_{IN} = 2.0V$		5		рF
Cout	Output	$V_{OUT} = 2.0V$		8		рF

- 1. Positive current is defined as into the terminal referenced.
- All voltages with respect to network ground.

- Duration of short circuit should not exceed 1 second.
 Typical values are at V_{CC} = 5V, T_A = +25°C.
 Measured with all inputs grounded and all outputs open.

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82LHS191

AC ELECTRICAL CHARACTERISTICS

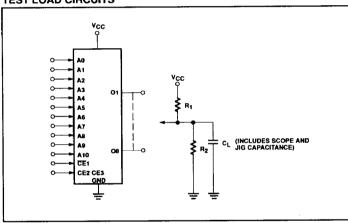
 $R_1 = 270\Omega$, $R_2 = 600\Omega$, $C_L = 30pF$, $0^{\circ}C \le T_A \le +75^{\circ}C$, $4.75V \le V_{CC} \le 5.25V$

7		METER TO	FROM	LIMITS			
SYMBOL PARAM	PARAMETER			Min	Typ ¹	Max	UNIT
Access time ²							
t _{AA}		Output	Address		30	35	ns
t _{CE}		Output	Chip Enable		15	20	ns
Disable time ³							
t _{CD}	· · · · · · · · · · · · · · · · · · ·	Output	Chip Disable		15	20	ns

NOTES:

- Typical values are at V_{CC} = 5V, T_A = +25°C.
 Tested at an address cycle time of 1μs.
- 3. Measured at a delta of 0.5V from Logic Level with $R_1 = 750\Omega$, $R_2 = 750\Omega$, $C_L = 5pF$.

TEST LOAD CIRCUITS



VOLTAGE WAVEFORMS

